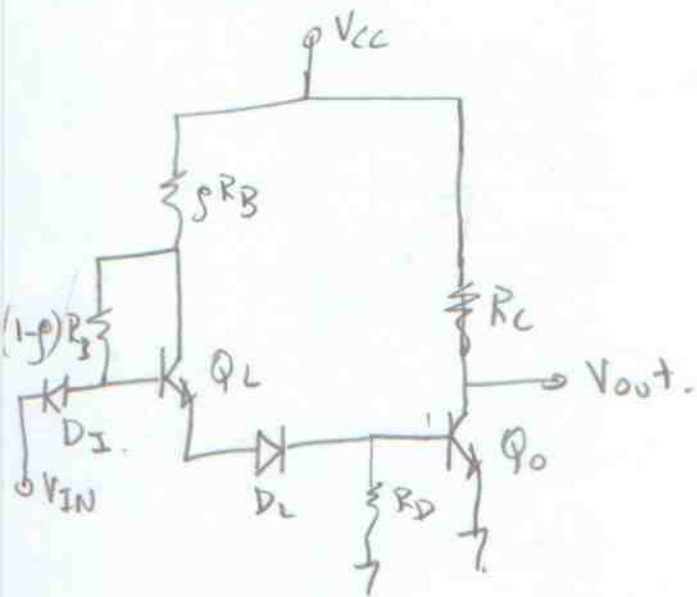


# Modified DTL :



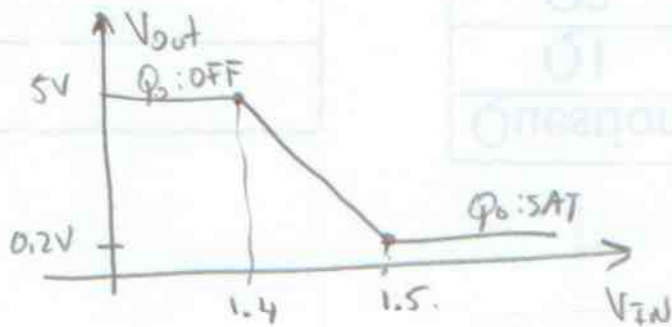
DTL with the following parameters is manufactured as 930 Series.

- $V_{CC} = 5V$
- $S R_B = 1.75 k\Omega$ ;  $R_C = 6 k\Omega$ .
- $(1-\beta) R_B = 2 k\Omega$ ;
- $R_D = 5 k\Omega$ ;
- $(\beta = 7/15)$

$0 < \beta < 1$ .

( $Q_L$ : Level shifting transistor).

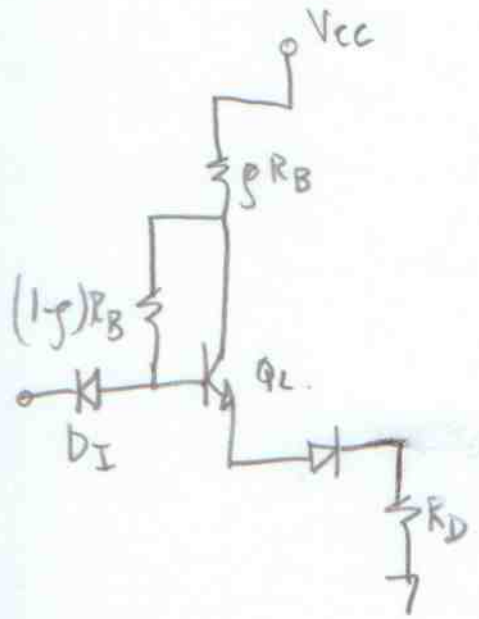
- ①  $Q_0$  turns ON when  $V_{RD} = 0.7V$ ;  $\rightarrow V_{IN} = 1.4V$ ; ← edge of conduction
- ②  $Q_0$  saturates (at the edge)  $V_{RD} = 0.8V$ ;  $\rightarrow V_{IN} = 1.5V$ ; ← edge of saturation.



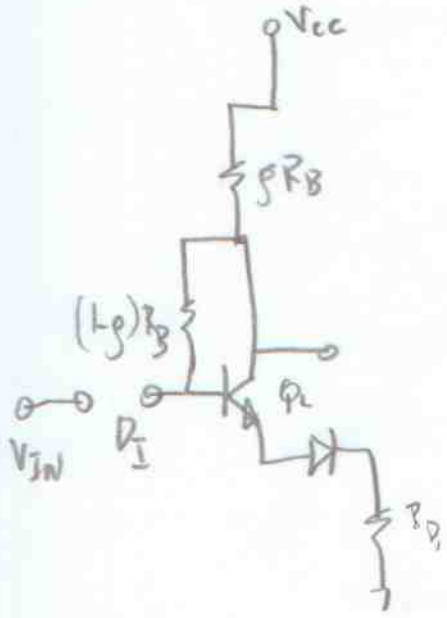
$Q_L$ : provides more current to  $Q_0$  since it's adjusted (biased) in self-biased configuration and remains in FA when  $V_{IN}$  is in  $[0V, 5V]$ .

(Current provided by  $Q_0$  improves Fan-out at O.L.)  
 "to be seen shortly"

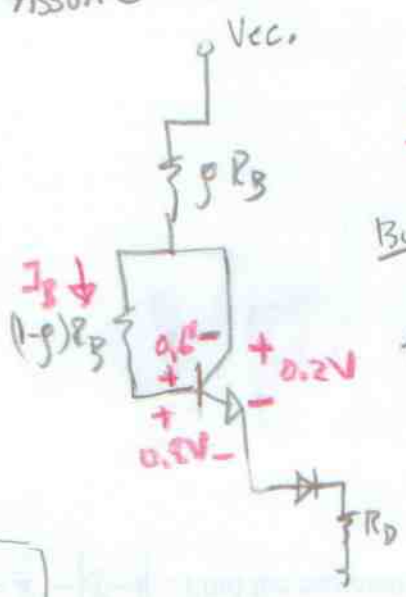
Let's analyze self-biased configuration.



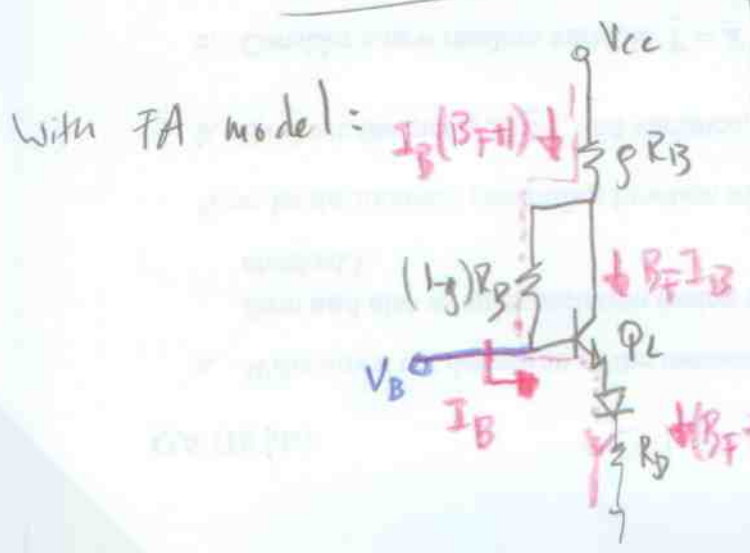
(1) Assume  $D_I$  is OFF



$Q_L$  has to be in FA  
 (since Assume SAT)



$I_B = \frac{-0.16}{(1-g)R_B} < 0$   
 $\frac{I_{B0}}{I_B} > 0$  for the transistor to be ON.  
 Hence SAT is not possible.



With FA model:

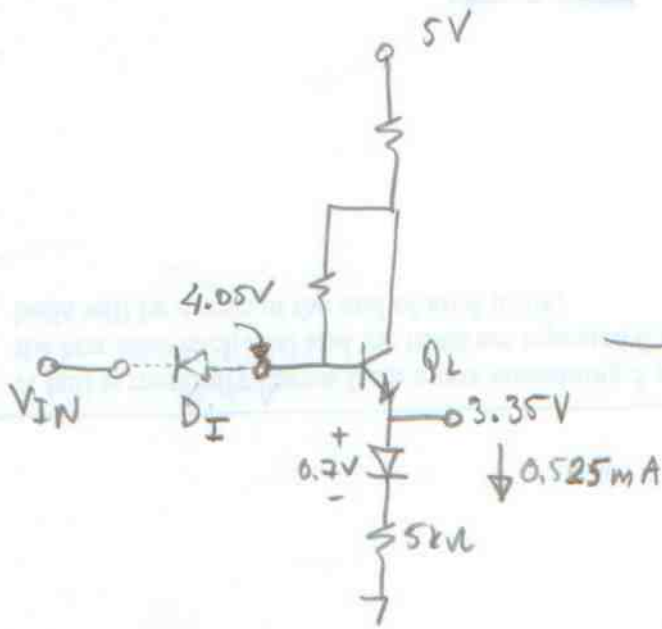
KVL along dotted line:

$$V_{cc} = I_B(B_F+1)gR_B + (1-g)R_B I_B + 0.7 + 0.7 + R_D(B_F+1)I_B$$

$$I_B = \frac{V_{cc} - 1.4}{(B_F+1)(gR_B + R_D) + (1-g)R_B}$$

Using 930 Series Parameters ( $\beta_F = 100$ )

$$I_B = \frac{5 - 1.4}{(101)(6.75) + 2} \text{ mA} = 5.25 \mu\text{A}$$

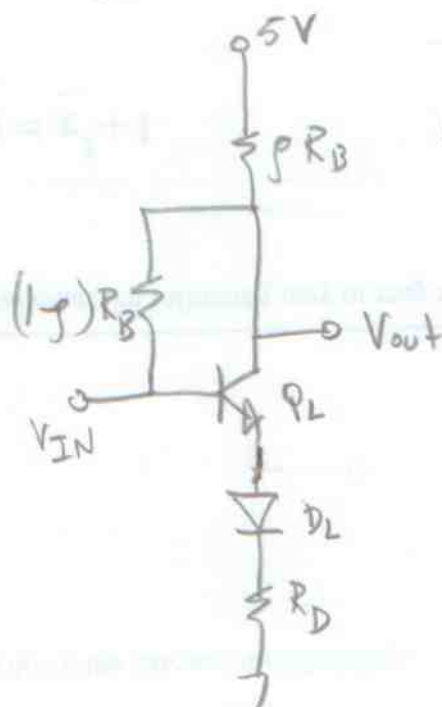


Then when

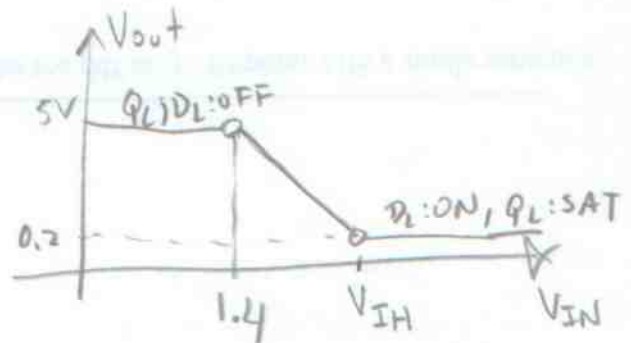
$$V_{IN} > 4.05 - 0.7 = 3.35 \text{ V}$$

$D_I$  turns OFF and the contact of  $V_{IN}$  to  $Q_L$  is cut-off.

As an exercise, assume that  $D_I$  diode is removed and we have the following configuration.

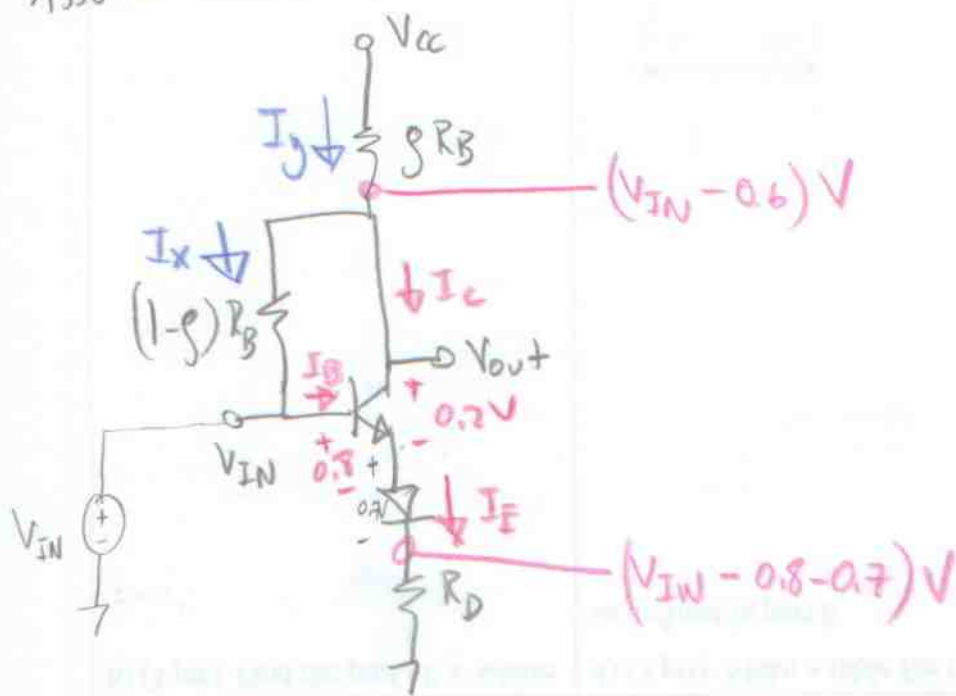


It's clear that the system has the following VTC.



Let's find  $V_{IH}$ :

Assume SAT



$$I_X = \frac{(V_{IN} - 0.6) - V_{IN}}{(1-g)R_B} = \frac{-0.6}{(1-g)R_B} \text{ A} ; I_Y = \frac{V_{CC} - (V_{IN} - 0.6)}{gR_B}$$

$$= \frac{V_{CC} + 0.6 - V_{IN}}{gR_B} \text{ A}$$

$$I_E = \frac{V_{IN} - 1.5}{R_D} \text{ A}$$

$$I_C = I_Y - I_X = \frac{V_{CC} + 0.6 - V_{IN}}{gR_B} + \frac{0.6}{(1-g)R_B} = \frac{V_{CC} - V_{IN}}{gR_B} + \frac{0.6}{g(1-g)R_B}$$

$$I_B = I_E - I_C = \frac{V_{IN} - 1.5}{R_D} - \left( \frac{V_{CC} - V_{IN}}{gR_B} + \frac{0.6}{g(1-g)R_B} \right)$$

For SAT conditions are.

- ①  $I_B > 0$  (ON)
- ②  $\beta I_B > I_C$  (Not FA)

Using 930 Series parameters:

64/E

$$I_B = \frac{V_{IN} - 1.5}{5} + \frac{V_{IN} - 5}{1.75} - \frac{0.6}{\frac{7}{15} \cdot 2} \text{ mA.}$$

$$I_B = \frac{V_{IN}(7+20) - 100 - 10.5 - 22.5}{35} \text{ mA.}$$

$$I_B = \frac{27V_{IN} - 132.5}{35} \text{ mA}$$

$$I_c = \frac{5 - V_{IN}}{7/4} + \frac{0.6}{7/15 \cdot 2} \text{ mA} = \frac{-4V_{IN} + 20 + 4.5}{7}$$

$$I_c = \frac{24.5}{7} - \frac{4}{7} V_{IN}$$

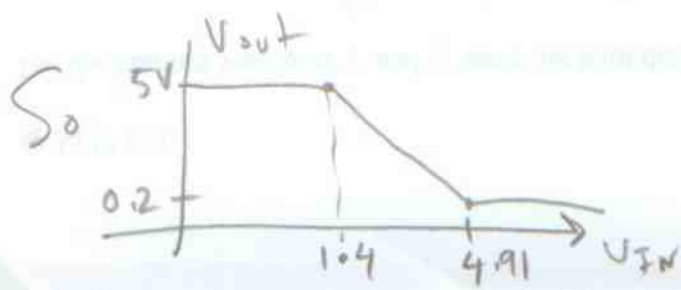
SAT condition:

$$\beta_F I_B > I_c \rightarrow \left( \frac{27V_{IN} - 132.5}{35} \right) 100 > \left( \frac{24.5}{7} - \frac{4}{7} V_{IN} \right)$$

$$20(27V_{IN} - 132.5) > (24.5 - 4V_{IN})$$

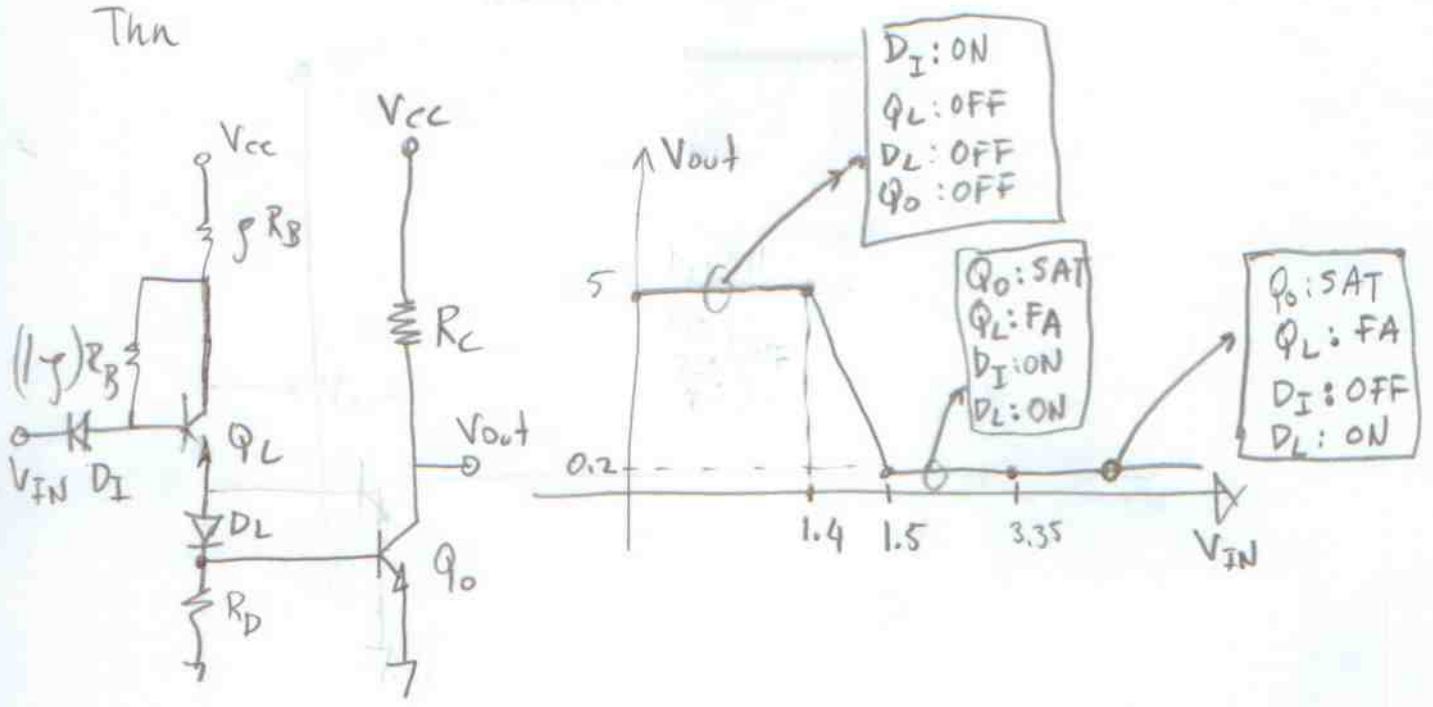
$$V_{IN} > \frac{20 \cdot (132.5) + 24.5}{544}$$

$$V_{IN} > 4.91 \text{ V}$$

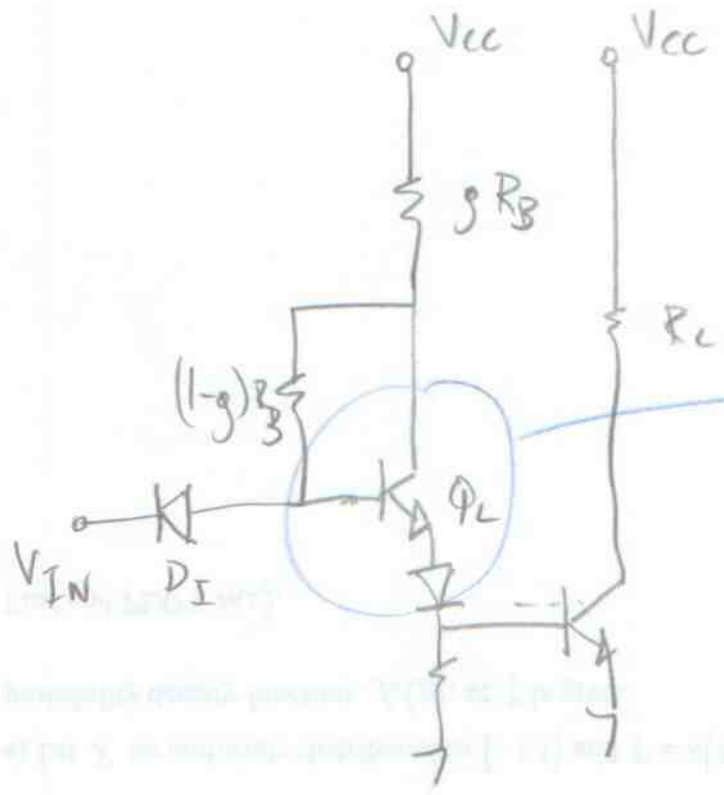


This concludes the exercise.

Thn



Note that



$Q_L$  is in FA mode when it is ON.  
 (Without  $D_I$ ,  $Q_L$  saturates at 4.91V; but with  $D_I$   $Q_L$  never saturates since  $V_{IN}$  is cut-off when  $V_{IN} > 3.35$ V)